

## Schottky Barrier Rectifiers

Using the Schottky Barrier principle with a appropriate barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

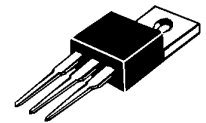
### Features

- \* Low Forward Voltage.
- \* Low Switching noise.
- \* High Current Capacity
- \* Guarantee Reverse Avalanche.
- \* Guard-Ring for Stress Protection.
- \* Low Power Loss & High efficiency.
- \* 150°C Operating Junction Temperature
- \* Low Stored Charge Majority Carrier Conduction.
- \* Plastic Material used Carries Underwriters Laboratory
- \* Flammability Classification 94V-O
- \* Pb free
- \* In compliance with EU RoHs directives

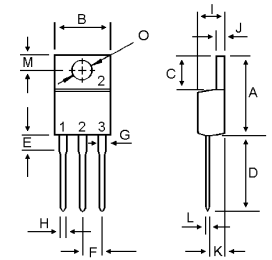


### SCHOTTKY BARRIER RECTIFIERS

**10 AMPERES  
60 VOLTS**



**TO-220AB**



DIM	MILLIMETERS	
	MIN	MAX
A	14.68	16.00
B	9.78	10.42
C	5.02	6.60
D	13.00	14.62
E	3.10	4.19
F	2.41	2.67
G	1.10	1.67
H	0.69	1.01
I	4.22	4.98
J	1.14	1.40
K	2.20	3.30
L	0.28	0.61
M	2.48	3.00
O	3.50	4.00

### MAXIMUM RATINGS

Characteristic	Symbol	SE10C60C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	60	V
RMS Reverse Voltage	$V_{R(RMS)}$	42	V
Average Rectifier Forward Current ( Per diode ) Total Device (Rated $V_R$ )	$I_{F(AV)}$	5 10	A
Peak Repetitive Forward Current (Rate $V_R$ , Square Wave, 20kHz)	$I_{FM}$	10	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-wave, single phase, 60Hz)	$I_{FSM}$	125	A
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-65 to +150	°C

### ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Maximum Instantaneous Forward Voltage ( $I_F = 5$ Amp $T_C = 25^\circ\text{C}$ ) ( $I_F = 5$ Amp $T_C = 125^\circ\text{C}$ )	$V_F$	---	0.65 0.56	0.70 ---	V
Typical Thermal Resistance junction to case	$R_{\theta jc}$		4.2		°C/w
Maximum Instantaneous Reverse Current ( Rated DC Voltage, $T_C = 25^\circ\text{C}$ ) ( Rated DC Voltage, $T_C = 125^\circ\text{C}$ )	$I_R$	---	0.01 8	0.5 ---	mA

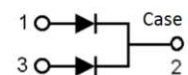


FIG-1 FORWARD CURRENT DERATING CURVE

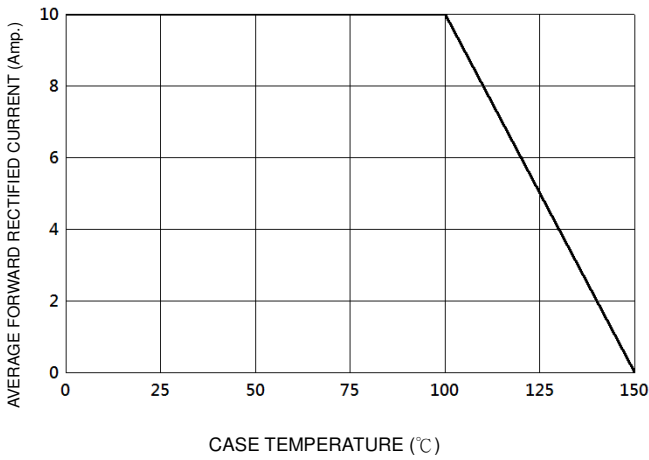


FIG-2 TYPICAL FORWARD CHARACTERISTICS

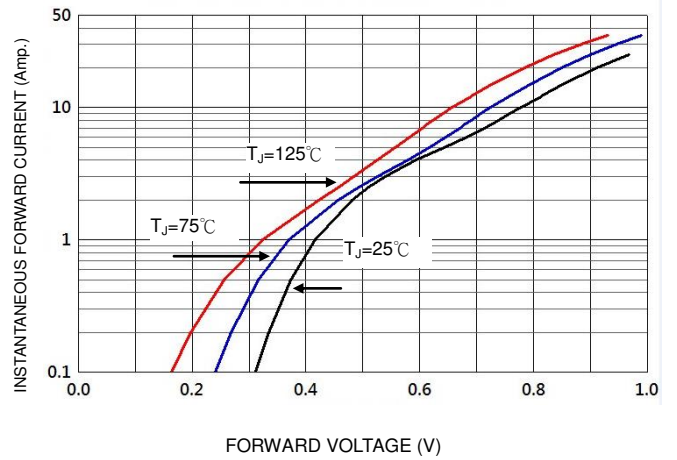


FIG-3 TYPICAL REVERSE CHARACTERISTICS

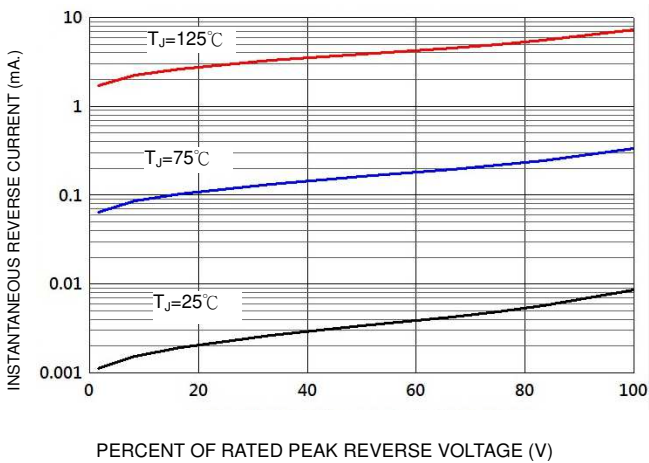


FIG-4 TYPICAL JUNCTION CAPACITANCE

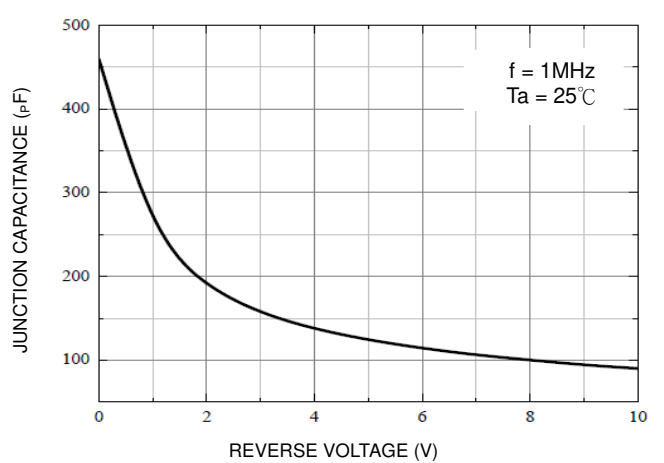
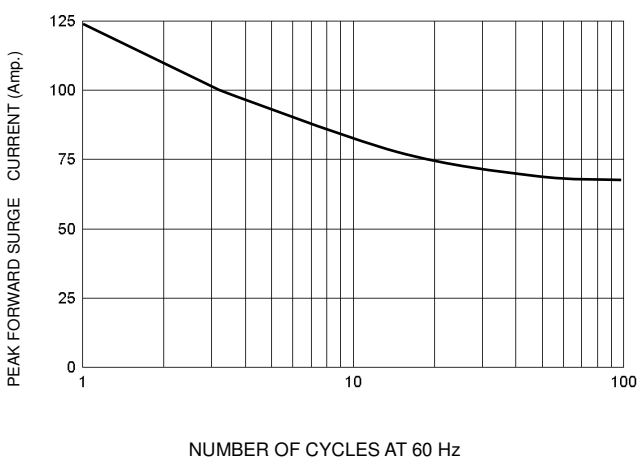


FIG-5 PEAK FORWARD SURGE CURRENT



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